#### **SDLS040**

# TRIPLE 3-INPUT POSITIVE-NAND GATES WITH OPEN-COLLECTOR OUTPUTS

DECEMBER 1983-REVISED MARCH 1988

- Package Options Include Plastic "Small Outline" Packages, Ceramic Chip Carriers and Flat Packages, and Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability

#### description

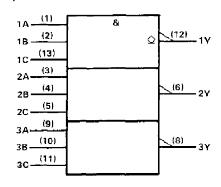
These devices contain three independent 3-input NANO gates with open-collector outputs. The open collector outputs require pull-up resistors to perform correctly. They may be connected to other open-collector outputs to implement active-low wired-OR or active-high wired-AND functions. Open-collector devices are often used to generate higher VOH levels.

The SN5412 and SN54LS12 are characterized for operation over the full military temperature range of  $-55\,^{\circ}\mathrm{C}$  to 125°C. The SN7412 and SN74LS12 are characterized for operation from 0°C to 70°C.

#### FUNCTION TABLE (each gate)

	NPUT	s	OUTPUT
А	В	С	Y
Н	Н	Н	L
L	X	Х	Н
х	L	X	н
Х	Х	L	н
i			

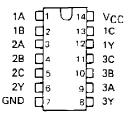
## logic symbol<sup>†</sup>



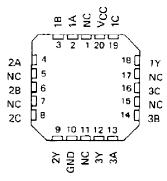
 $<sup>^\</sup>dagger$  This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for D, J, N, and W packages.

SN5412, SN54LS12...J OR W PACKAGE SN7412...N PACKAGE SN74LS12...D OR N PACKAGE (TOP VIEW)

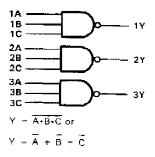


# SN54LS12 . . . FK PACKAGE (TOP VIEW)



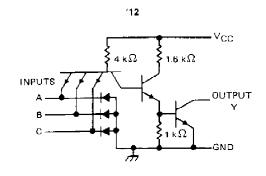
NC-No internal connection

## logic diagram (positive logic)

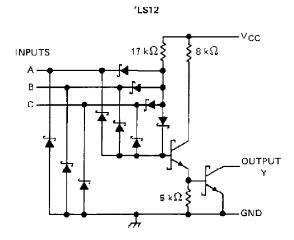


# TRIPLE 3-INPUT POSITIVE-NAND GATES WITH OPEN-COLLECTOR OUTPUTS

## schematics (each gate)



Resistor values shown are nominal.



## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (see Note 1	1)
Input voltage: '12	5.5 V
′LS12	7 V
	7 V
Operating free-air temperature:	SN54'
	\$N74' 0°C to 70°C
Storage temperature range	

NOTE 1: Voltage values are with respect to network ground terminal.

## SN5412, SN5412 TRIPLE 3-INPUT POSITIVE NAND GATES WITH OPEN COLLECTOR OUTPUTS

## recommended operating conditions

		SN5412			SN7412			
	MIN	NOM	MAX	MIN	NOM	MAX	TINU	
V <sub>CC</sub> Supply voltage	4.5	5	5.5	4.75	5	5.25	٧	
VIH High-level input voltage	2			2			٧	
V <sub>1L</sub> Low-level input voltage			8.0		• • • •	0.8	٧	
VOH High-level output voltage			5.5			5,5	V	
IOL Low-level output current			16	-		16	mΑ	
TA Operating free-air temperature	- 55		125	0		70	∘c	

### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	SN5412	SN7412	
	1691 CONDITIONS	MIN TYP <sup>‡</sup> MAX	MIN TYP <sup>‡</sup> MAX	UNIT
VIK	$V_{CC} = MIN$ , $I_{\parallel} = -12 \text{ mA}$	-1.5	- 1.5	٧
юн	V <sub>CC</sub> = MIN, V <sub>IL</sub> = 0.8 V, V <sub>OH</sub> = 5.5 V		0.25	A
	$V_{CC} = MIN$ , $V_{IL} = 0.7 \text{ V}$ , $V_{OH} = 5.5 \text{ V}$	0.25		mΑ
VOL	VCC - MIN, VIH - 2 V, IOL = 16 mA	0.2 0.4	0.2 0.4	V
J <sub>1</sub>	VCC = MAX, VI = 5.5 V	1	1	mA
ΊΗ	$V_{CC} = MAX$ , $V_I = 2.4 V$	40	40	μА
l <sub>IL</sub>	VCC = MAX, VI = 0.4 V	-1.6	-1.6	mA
ССН	$V_{CC} = MAX, V_I = 0$	3 6	3 6	mA
<sup>1</sup> CCL	$V_{CC} = MAX$ , $V_{I} = 4.5 V$	9 16.5	9 16.5	mA

 $<sup>^{\</sup>dagger}$ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.  $^{\ddagger}$ All typical values are at  $^{\lor}$ CC = 5 V,  $^{\lor}$ CA = 25  $^{\circ}$ C.

## switching characteristics, VCC = 5 V, $TA = 25^{\circ}C$ (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS		MIN	ТҮР	MAX	UNIT
<sup>t</sup> PLH	A. B or C	, ,	R <sub>L</sub> = 4 kΩ,	C <sub>L</sub> = 15 pF		35	45	ns
<sup>†</sup> PH∟	, , , a o i a	·	R <sub>L</sub> = 400 Ω,	C <u>L</u> = 15 pF		8	15	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

# SN54LS12, SN74LS12 TRIPLE 3-INPUT POSITIVE-NAND GATES WITH OPEN-COLLECTOR OUTPUTS

## recommended operating conditions

	:	SN54LS12			\$N74LS12		
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT
V <sub>CC</sub> Supply voltage	4.5	5	5.5	4.75	5	5.25	V
VIH High-level input voltage	2			2			. ٧
V <sub>IL</sub> · Low-level input voltage			0.7			8.0	٧
VOH High-level output voltage			5.5			5.5	٧
IOL Low-level output current			4			8	mΑ
TA Operating free-air temperature	- <b>55</b>		125	٥		70	°C

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS †			SN54LS12			SN74LS12			
			MIN	TYP‡	MAX	MIN	TYP\$	MAX	UNIT	
VIΚ	VCC - MIN,	I <sub>1</sub> = - 18 mA				- 1.5			- 1.5	V
<sup>1</sup> ОН	V <sub>CC</sub> = MIN,	VIL = MAX,	V <sub>OH</sub> = 5.5 V			0.1			0.1	mΑ
VOI	VCC = MIN.	V <sub>1H</sub> = 2 V,	1 <sub>OL</sub> = 4 mA		0.25	0.4		0.25	0.4	V
	V <sub>CC</sub> = MIN,	V <sub>IH</sub> ≈ 2 V,	1 <sub>OL</sub> = 8 mA					0.35	0.5	] "
11	V <sub>CC</sub> = MAX,	V <sub> </sub> = 7 V				0.1			0.1	mA
11H	V <sub>CC</sub> - MAX,	V <sub> </sub> = 2.7 V	<u> </u>			20			20	μА
ηL	V <sub>CC</sub> = MAX,	V <sub> </sub> = 0.4 V				- 0.4		,	- 0.4	mA
ıссн	V <sub>CC</sub> = MAX,	V( = 0			- 0.7	1.4		0.7	1.4	mA
¹ccr	V <sub>CC</sub> = MAX,	V <sub>1</sub> = 4.5 V			1,8	3,3		1.8	3,3	mA

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions. ‡ All typical values are at  $V_{CC} = 6 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

# switching characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$ (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN TYP	MAX	UNIT
tPLH	A. B or C	٧	H <sub>L</sub> = 2 kΩ, C <sub>L</sub> = 15 pF	17	32	ns
tPH L	71, 2 0			15	28	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



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